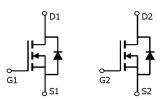


Feature

20V,6.0A

$$\begin{split} &R_{\text{DS (ON)}} < 26\text{m}\,\Omega\,\text{@V}_{\text{GS}} = 4.5\text{V} & \text{TYP=20 m}\,\Omega \\ &R_{\text{DS (ON)}} < 33\text{m}\,\Omega\,\text{@V}_{\text{GS}} = 2.5\text{V} & \text{TYP=26 m}\,\Omega \end{split}$$

- Advanced Trench Technology
- Lead free product is acquired
- Low gate charge



Schematic Diagram

Application

- Interfacing Switching
- Load Switching
- Power management



Marking and pin Assignment

Package Marking and Ordering Information

Device Marking	Device Marking Device		Device Package Reel Size		Quantity (PCS)	
8205A	AP8205A	TSSOP-8	-	-	5000	

ABSOLUTE MAXIMUM RATINGS (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current (T _a =25℃)	I _D	6.0	А
Continuous Drain Current (T _a =70℃)	I _D	4.0	А
Pulsed Drain Current	I _{DM}	24	А
Power Dissipation	P _D	2.5	W
Thermal Resistance from Junction to Ambient ⁽⁴⁾	R _{θJA}	50	°C/W
Junction Temperature	TJ	150	$^{\circ}$
Storage Temperature	T _{STG}	-55~ +150	$^{\circ}$



MOSFET ELECTRICAL CHARACTERISTICS(T_J=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 250\mu A$	20	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =20V, V _{GS} = 0V	-	-	1	μA
Gate-body leakage current	I _{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage ⁽³⁾	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.5	0.7	1.2	V
Drain-source on-resistance ⁽³⁾	В	V _{GS} =4.5V, I _D =4A	-	20	26	mΩ
Dialii-Source on-resistance.	R _{DS(on)}	V _{GS} =2.5V, I _D =3A	-	26	33	
Dynamic characteristics						
Input Capacitance	C _{iss}	V _{DS} =20V, V _{GS} =0V, f =1MHz	-	1035	-	pF
Output Capacitance	C _{oss}		-	320	-	
Reverse Transfer Capacitance	C _{rss}	_	-	150	-	
Switching characteristics						
Turn-on delay time	t _{d(on)}		-	30	-	
Turn-on rise time	t _r	V_{DD} =10V, I_{D} =1A, V_{GS} =5.0V, R_{G} =6 Ω	-	70	-	ns
Turn-off delay time	t _{d(off)}		-	40	-	
Turn-off fall time	t _f	-	-	65	-	
Total Gate Charge	Qg	VD0 40V/ ID 0.54	-	15	-	nC
Gate-Source Charge	Qgs	VDS=10V, ID=3.5A,	-	2.9	-	
Gate-Drain Charge	Qgd	- VGS=4.5V	-	3.6	-	
Source-Drain Diode characteristics	·		<u> </u>			
Diode Forward voltage ⁽³⁾	V _{DS}	V _{GS} =0V, I _S =1.7A	-	-	1.2	V
Diode Forward current ⁽⁴⁾	Is		-	-	6.0	Α

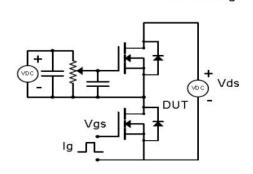
Notes:

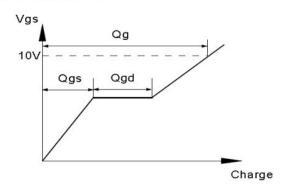
- 1. Repetitive Rating: pulse width limited by maximum junction temperature
- 2. Pulse Test: pulse width≤300µs, duty cycle≤2%
- 3. Surface Mounted on FR4 Board,t≤10 sec



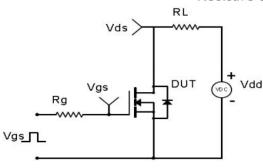
Test Circuit & Waveform

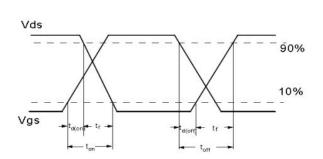
Gate Charge Test Circuit & Waveform



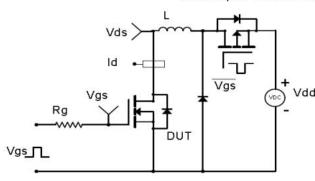


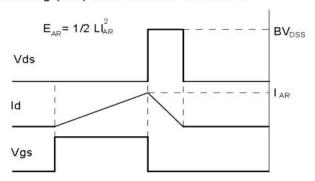
Resistive Switching Test Circuit & Waveforms



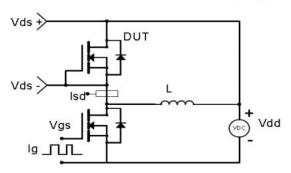


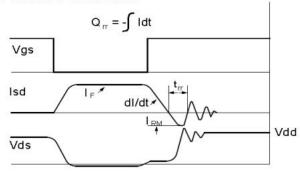
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





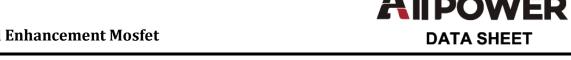
Diode Recovery Test Circuit & Waveforms

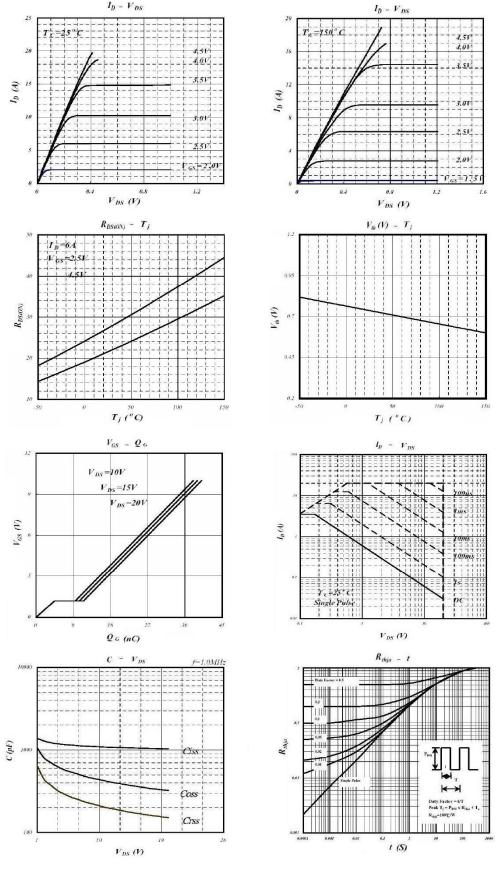






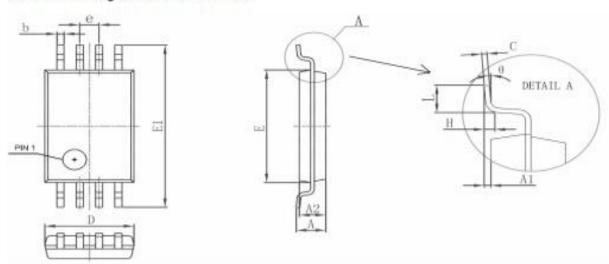
Typical Performance Characteristics





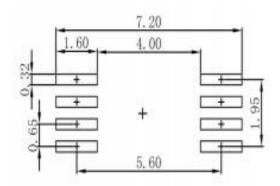


TSSOP-8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
D	2.900	3.100	0.114	0.122
E	4.300	4.500	0.169	0.177
b	0.190	0.300	0.007	0.012
С	0.090	0.200	0.004	0.008
E1	6.250	6.550	0.246	0.258
Α		1.200	3000-010-01	0.047
A2	0.800	1.000	0.031	0.039
A1	0.050	0.150	0.002	0.006
е	0.65(BSC)	0.026	(BSC)
L	0.500	0.700	0.020	0.028
н	0.25(TYP)		0.01(TYP)	
θ	1°	7°	1°	7°

TSSOP-8 Suggested Pad Layout



Note:

1.Controlling dimension: in millimeters

2.General tolerance: ±0.05mm

3. The pad layout is for reference purposes only



Revision History

Revision	Release	Remark	
V1.0	2024/03/16	Initial Release	

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which

requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.